

VII. Phone

→ **Spindle model** → only for nearly-free e^-
 or
 tight-binding models,

electronic band - empty
↓
Assuming non-interacting
↓
 $C_V = N \frac{3}{2} k_B$ specific heat
↓
Fermi - Dirac distribution

non-interacting fermions
 $f_F(\epsilon) = \frac{1}{e^{\beta(\epsilon - \mu)} + 1}$
 Total energy of e-

$U = 2 \sum_k E_k f_{FD}(E_k)$
 $\therefore C_V = 2 \omega N k_B \frac{k_B T}{E_F}$

Transport properties

↓
Impurities (T ≠ 0)
↓
R = $\frac{V}{I}$
↓
R = ∞, R = 0 (insulators) (metal)

$C_n(k) = \begin{cases} \text{elena} & \text{Re-} \\ \text{Teikna} & n \geq 0 \end{cases}$

Diodes/transistors

n-wakes
↓
w/e-

p-wakes
↓
w/holes